TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP3041, TLP3042, TLP3043

Office Machine
Household Use Equipment
Triac Driver
Solid State Relay

The TOSHIBA TLP3041, TLP3042 and TLP3043 consist of a zero voltage crossing turn—on photo—triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

- Peak off-state voltage: 400V(min.)
- Trigger LED current: 15mA(max.) (TLP3041)

10mA(max.) (TLP3042) 5mA(max.) (TLP3043)

- On-state current: 100mA(max.)
- UL recognized: UL1577, file no. E67349 Isolation voltage: 5000Vrms(min.)
- Option (D4) type

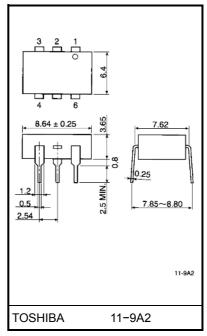
VDE approved: DIN VDE0884 / 08.87, certificate no. 68329

Maximum operating insulation voltage: 630VpK Highest permissible over voltage: 6000VpK

(Note) When a VDE0884 approved type is needed, please designate the "option (D4)"

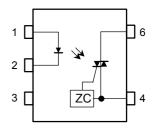
		7.62mm pich	10.16mm pich
		standard type	(LF2) type
•	Creepage distance:	7.0mm(min.)	8.0mm(min.)
	Clearance:	7.0mm(min.)	8.0mm(min.)
	Insulation thickness:	0.5mm(min.)	0.5mm(min.)

Unit in mm



Weight: 0.44 g

Pin Configuration(top view)



- 1: Anode
- 2 : Cathode
- 3: NC
- 4: Terminal 1
- 6: Terminal 2



Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current		lF	50	mA
	Forward current derating (Ta ≥ 53°C)		Δl _F / °C	-0.7	mA / °C
	Peak forward current (100µs pulse, 100pps)		I _{FP}	1	А
LED	Power dissipation		P_{D}	100	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _D / °C	-1.0	mW / °C	
	Reverse voltage	V_{R}	5	V	
	Junction temperature	Tj	125	°C	
	Off–state output terminal voltage		V_{DRM}	400	٧
	On-state RMS current	Ta=25°C	IT(DMO)	100	mA
		Ta=70°C	I _{T(RMS)}	50	IIIA
_	On–state current derating (Ta ≥ 25°C)		ΔI _T / °C	-1.1	mA / °C
Detector	Peak on-state current (100µs pulse, 120pps)		I _{TP}	2	А
	Peak nonrepetitive surge current (P _w =10ms, DC=10%)		I _{TSM}	1.2	А
	Power dissipation		P_{D}	300	mW
	Power dissipation derating (Ta ≥ 25°C)		ΔP _D / °C	-4.0	mW / °C
	Junction temperature		Tj	115	°C
Storag	e temperature range	T _{stg}	-55~150	°C	
Operating temperature range			T _{opr}	−40~100	°C
Lead soldering temperature (10s)			T _{sol}	260	°C
Total package power dissipation			PT	330	mW
	Total package power dissipation derating(Ta ≥ 25°C)			-4.4	mW / °C
	Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)			5000	Vrms

(Note 1) Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4 and 6 shorted together.

Recommended Operating Conditions¥

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	_	_	120	Vac
Forward current	I _F *	15	20	25	mA
Peak on-state current	I _{TP}	_	_	1	Α
Operating temperature	T _{opr}	-25	_	85	°C

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※ In the case of TLP3042



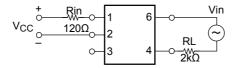
Individual Electrical Characteristics (Ta = 25°C)

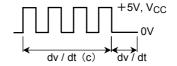
	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 10mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1MHz	_	10	_	pF
	Peak off-state current	I _{DRM}	V _{DRM} = 400V	_	10	100	nA
	Peak on-state voltage	V_{TM}	I _{TM} = 100mA	_	1.7	3.0	V
<u>_</u>	Holding current	lΗ	_	_	0.6	_	mA
Detector	Critical rate of rise of off–state voltage dv / dt	V _{in} = 120Vrms, Ta = 85°C (Fig.1)	200	500	_	V / µs	
	Critical rate of rise of commutating voltage	dv / dt(c)	V_{in} = 30Vrms, I_T = 15mA (Fig.1)	_	0.2		V / µs

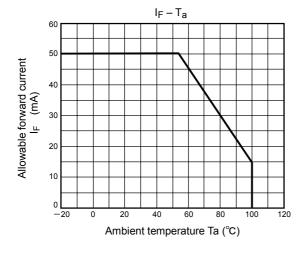
Coupled Electrical Characteristics (Ta = 25°C)

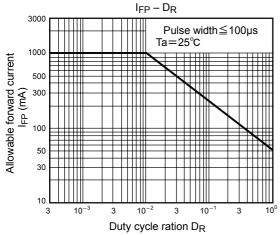
Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
	TLP3041	lFT	V _T = 3V	_	_	15	mA
Trigger LED current	TLP3042			_	5	10	
	TLP3043			_	_	5	
Inhibit voltage		V _{IH}	I _F = rated I _{FT}	_	_	40	V
Leakage in inhibited state		l _{IH}	I _F = rated I _{FT} V _T = rated V _{DRM}	_	100	300	μΑ
Capacitance input to output		CS	V _S = 0, f = 1MHz	_	0.8	_	pF
Isolation resistance		R _S	V _S = 500V (R.H. ≤ 60%)	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage		BVS	AC, 1 minute	5000	_	-	Vrms
			AC, 1 second (in oil)	_	10000	_	
			DC, 1 minute (in oil)	-	10000	1	V _{dc}

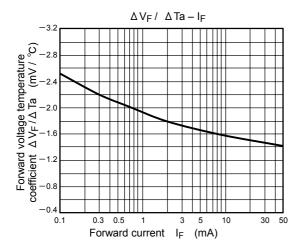
Fig.1 dv / dt test circuit

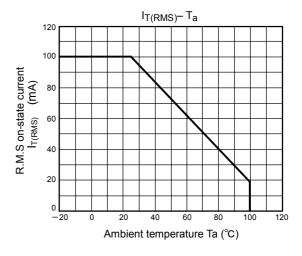


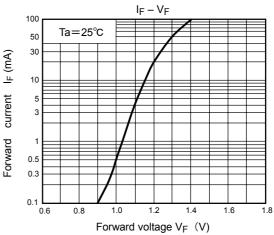


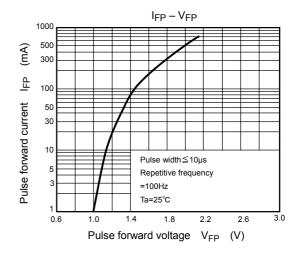


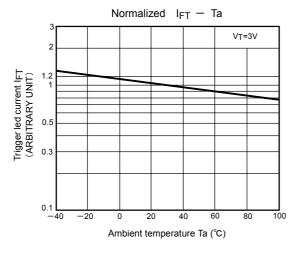


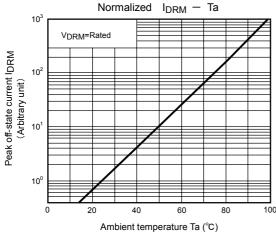


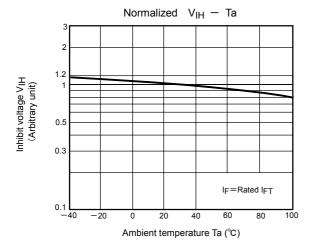


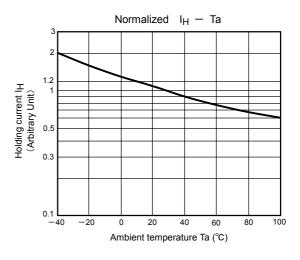


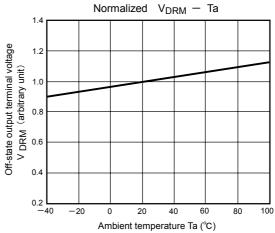


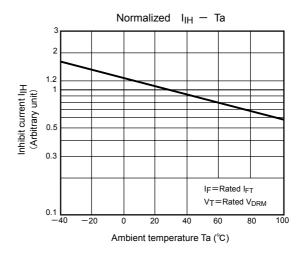












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RESTRICTIONS ON PRODUCT USE

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